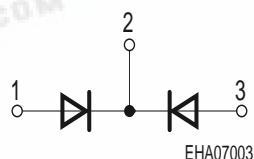
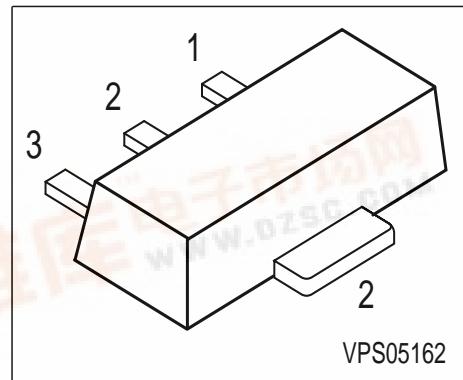


**BAW79A...BAW79D****Silicon Switching Diodes**

- Switching applications
- High breakdown voltage
- Common cathode



Type	Marking	Pin Configuration			Package
BAW79A	GE	1 = A1	2 = C1/2	3 = A2	SOT89
BAW79B	GF	1 = A1	2 = C1/2	3 = A2	SOT89
BAW79C	GG	1 = A1	2 = C1/2	3 = A2	SOT89
BAW79D	GH	1 = A1	2 = C1/2	3 = A2	SOT89

**Maximum Ratings**

Parameter	Symbol	BAW 79A	BAW 79B	BAW 79C	BAW 79D	Unit
Diode reverse voltage	$V_R$	50	100	200	400	V
Peak reverse voltage	$V_{RM}$	50	100	200	400	
Forward current	$I_F$		1			A
Peak forward current	$I_{FM}$			1		
Surge forward current, $t = 1 \mu s$	$I_{FS}$			10		
Total power dissipation, $T_S = 115^\circ C$	$P_{tot}$			1		W
Junction temperature	$T_j$			150		$^\circ C$
Storage temperature	$T_{stg}$			-65 ... 150		

**Thermal Resistance**

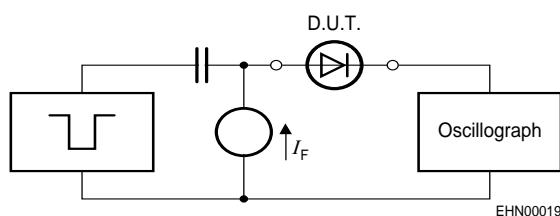
Junction - soldering point <sup>1)</sup>	$R_{thJS}$	$\leq 35$	K/W
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<sup>1</sup>For calculation of  $R_{thJA}$  please refer to Application Note Thermal Resistance

**Electrical Characteristics** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
<b>DC characteristics</b>					
Breakdown voltage $I_{(\text{BR})} = 100 \mu\text{A}$	$V_{(\text{BR})}$	50	-	-	V
	BAW79A	100	-	-	
	BAW79B	200	-	-	
	BAW79C	400	-	-	
	BAW79D				
Forward voltage $I_F = 1 \text{ A}$ $I_F = 2 \text{ A}$	$V_F$	-	-	1.6	
		-	-	2	
Reverse current $V_R = V_{R\text{max}}$	$I_R$	-	-	1	$\mu\text{A}$
Reverse current $V_R = V_{R\text{max}}, T_A = 150^\circ\text{C}$	$I_R$	-	-	50	
<b>AC characteristics</b>					
Diode capacitance $V_R = 0 \text{ V}, f = 1 \text{ MHz}$	$C_D$	-	10	-	pF
Reverse recovery time $I_F = 200 \text{ mA}, I_R = 200 \text{ mA}, R_L = 100 \Omega$ , measured at $I_R = 20 \text{ mA}$	$t_{rr}$	-	1	-	$\mu\text{s}$

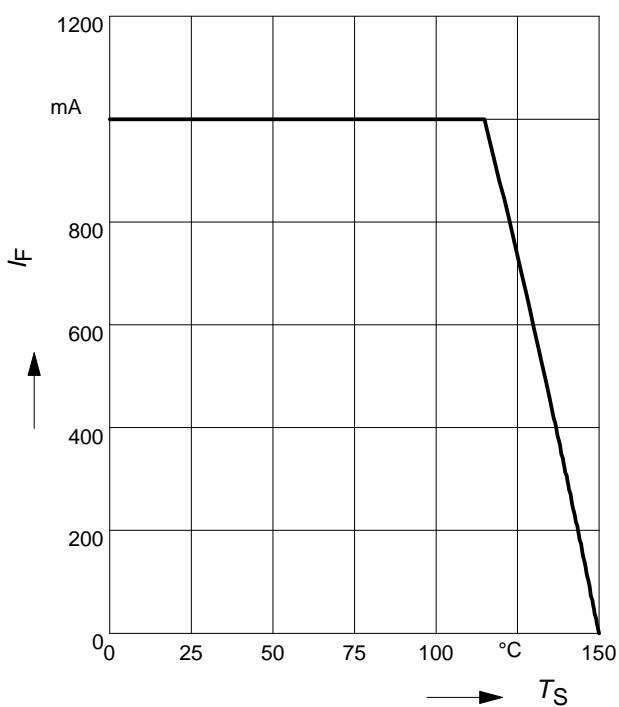
### Test circuit for reverse recovery time



Pulse generator:  $t_p = 10\mu\text{s}$ ,  $D = 0.05$ ,  
 $t_f = 0.6\text{ns}$ ,  $R_i = 50\Omega$

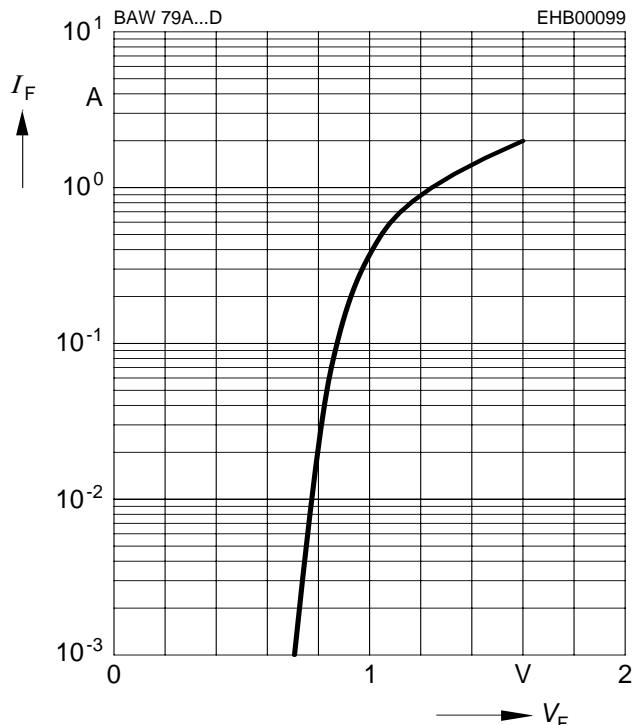
Oscilloscope:  $R = 50\Omega$ ,  $t_f = 0.35\text{ns}$ ,  
 $C \leq 1\text{pF}$

**Forward current  $I_F = f(T_S)$**



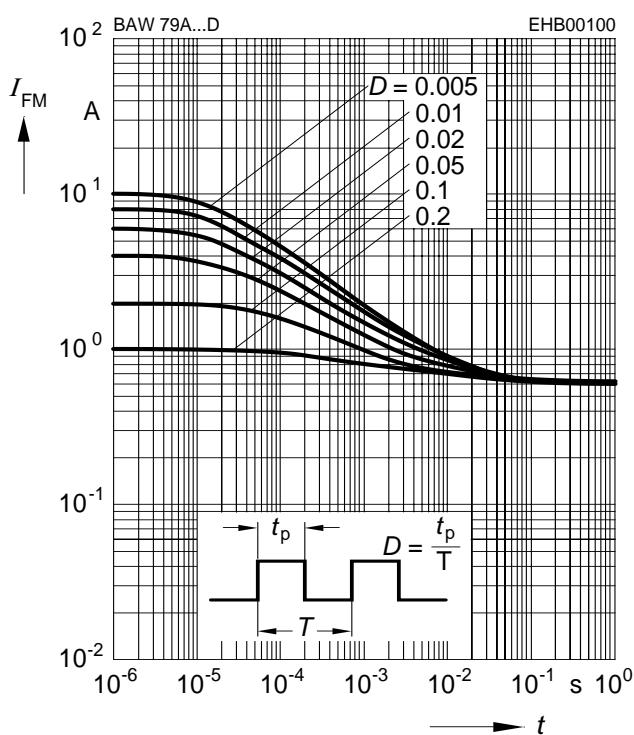
**Forward current  $I_F = f(V_F)$**

$T_A = 25^\circ\text{C}$



**Peak forward current  $I_{FM} = f(t_p)$**

$T_A = 25^\circ\text{C}$



**Reverse current  $I_R = f(T_A)$**

$V_R = V_{Rmax}$

